![Texas Instruments] **TEXAS INSTRUMENTS**
www.ti.com

TRSF3221E
3-V TO 5.5-V SINGLE-CHANNEL RS-232 1-Mbit/s LINE DRIVER/RECEIVER
WITH ±15-kV IEC ESD PROTECTION
SLLS822−JULY 2007

FEATURES

- **ESD Protection for RS-232 Pins**
  - ±15-kV Human-Body Model (HBM)
  - ±8-kV IEC 61000-4-2 Contact Discharge
  - ±15-kV IEC 61000-4-2 Air-Gap Discharge
- **Operates With 3-V to 5.5-V V_{CC} Supply**
- **Operates up to 1 Mbit/s**
- **Low Standby Current . . . 1 µA Typ**
- **External Capacitors . . . 4 × 0.1 µF**
- **Accepts 5-V Logic Input With 3.3-V Supply**
- **RS-232 Bus-Pin ESD Protection Exceeds ±15 kV Using HBM**
- **Auto-Powerdown Feature Automatically Disables Drivers for Power Savings**

APPLICATIONS

- **Battery-Powered, Hand-Held, and Portable Equipment**
- **PDAs and Palmtop PCs**
- **Notebooks, Sub-Notebooks, and Laptops**
- **Digital Cameras**
- **Mobile Phones and Wireless Devices**

DB OR PW PACKAGE
(TOP VIEW)

$\overline{EN}$	1		16	$\overline{FORCEOFF}$
C1+	2		15	V_{CC}
V+	3		14	GND
C1−	4		13	DOUT
C2+	5		12	FORCEON
C2−	6		11	DIN
V−	7		10	$\overline{INVALID}$
RIN	8		9	ROUT

DESCRIPTION/ORDERING INFORMATION

The TRSF3221E consists of one line driver, one line receiver, and a dual charge-pump circuit with ±15-kV IEC ESD protection pin to pin (serial-port connection pins, including GND). The TRSF3221E provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The TRSF3221E operates at data signaling rates up to 1 Mbit/s and a driver output slew rate of 24 V/µs to 150 V/µs.

Flexible control options for power management are available when the serial port is inactive. The auto-powerdown feature functions when FORCEON is low and $\overline{FORCEOFF}$ is high. During this mode of operation, if the TRSF3221E does not sense a valid RS-232 signal on the receiver input, the driver output is disabled. If $\overline{FORCEOFF}$ is set low and the enable ($\overline{EN}$) input is high, both the driver and receiver are shut off, and the supply current is reduced to 1 µA. Disconnecting the serial port or turning off the peripheral drivers causes the auto-powerdown condition to occur. Auto-powerdown can be disabled when FORCEON and $\overline{FORCEOFF}$ are high. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to the receiver input. The $\overline{INVALID}$ output notifies the user if an RS-232 signal is present at the receiver input. $\overline{INVALID}$ is high (valid data) if the receiver input voltage is greater than 2.7 V or less than −2.7 V, or has been between −0.3 V and 0.3 V for less than 30 µs. $\overline{INVALID}$ is low (invalid data) if the receiver input voltage is between −0.3 V and 0.3 V for more than 30 µs. See Figure 5 for receiver input levels.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 2007, Texas Instruments Incorporated

TEXAS
INSTRUMENTS
www.ti.com

ORDERING INFORMATION

T$_A$	PACKAGE[1][2]		ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 70°C	SSOP – DB	Reel of 2000	TRSF3221ECDBR	RT21EC
	TSSOP – PW	Tube of 90	TRSF3221ECPW	RT21EC
		Reel of 2000	TRSF3221ECPWR	
−40°C to 85°C	SSOP – DB	Reel of 2000	TRSF3221EIDBR	RT21EI
	TSSOP – PW	Tube of 90	TRSF3221EIPW	RT21EI
		Reel of 2000	TRSF3221EIPWR	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

FUNCTION TABLES

Each Driver[1]

INPUTS				OUTPUT DOUT	DRIVER STATUS
DIN	FORCEON	$\overline{\text{FORCEOFF}}$	VALID RIN RS-232 LEVEL		
X	X	L	X	Z	Powered off
L	H	H	X	H	Normal operation with auto-powerdown disabled
H	H	H	X	L	
L	L	H	Yes	H	Normal operation with auto-powerdown enabled
H	L	H	Yes	L	
L	L	H	No	Z	Powered off by auto-powerdown feature
H	L	H	No	Z	

(1) H = high level, L = low level, X = irrelevant, Z = high impedance

Each Receiver[1]

INPUTS			OUTPUT ROUT
RIN	$\overline{\text{EN}}$	VALID RIN RS-232 LEVEL	
L	L	X	H
H	L	X	L
X	H	X	Z
Open	L	No	H

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = disconnected input or connected driver off

Submit Documentation Feedback

TEXAS INSTRUMENTS
www.ti.com

TRSF3221E
3-V TO 5.5-V SINGLE-CHANNEL RS-232 1-Mbit/s LINE DRIVER/RECEIVER
WITH ±15-kV IEC ESD PROTECTION
SLLS822−JULY 2007

LOGIC DIAGRAM (POSITIVE LOGIC)

TEXAS INSTRUMENTS
www.ti.com
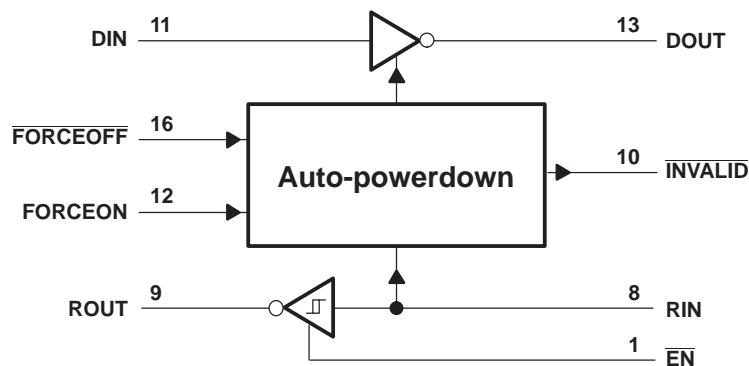
Table 1. 1-Mbit/s RS-232 Parts

PART NO.	TEMPERATURE RANGE	DRIVER NO.	RECEIVER NO.	ESD	SUPPLY V_{CC} (V)	FEATURE	PIN/PACKAGE
TRSF3221E	0°C to 70°C	1	1	±15-kV Air-Gap, ±8-kV Contact, ±15-kV HBM	3.3 or 5	Auto-powerdown	16-pin SOIC, SSOP, TSSOP
TRSF3232E		2	2	±15-kV Air-Gap, ±8-kV Contact, ±15-kV HBM	3.3 or 5	Low pin count	16-pin SOIC, SSOP, TSSOP
TRS3227		1	1	±8-kV Air-Gap, ±8-kV Contact, ±15-kV HBM	3.3 or 5	Auto-powerdown plus, ready signal	16-pin SSOP
TRSF3221		1	1	±15-kV HBM	3.3 or 5	Auto-powerdown	16-pin SOIC, SSOP, TSSOP
TRSF3223		2	2	±15-kV HBM	3.5 or 5	Auto-powerdown, enable signal	20-pin SOIC, SSOP, TSSOP
TRSF3222		2	2	±15-kV HBM	3.3 or 5	Enable, powerdown signal	20-pin SOIC, SSOP, TSSOP
TRSF3232		2	2	±15-kV HBM	3.3 or 5	Low pin count	16-pin SOIC, SSOP, TSSOP
TRSF3238		5	3	±15-kV HBM	3.3 or 5	Auto-powerdown plus	28-pin SOIC, SSOP, TSSOP
TRSF3243		3	5	±15-kV HBM	3.3 or 5	Auto-powerdown	28-pin SOIC, SSOP, TSSOP
TRSF3221E	−40°C to 85°C	1	1	±15-kV Air-Gap, ±8-kV Contact, ±15-kV HBM	3.3 or 5	Auto-powerdown	16-pin SOIC, SSOP, TSSOP
TRSF3232E		2	2	±15-kV Air-Gap, ±8-kV Contact, ±15-kV HBM	3.3 or 5	Low pin count	16-pin SOIC, SSOP, TSSOP
TRS3227		1	1	±8-kV Air-Gap, ±8-k V Contact, ±15-kV HBM	3.3 or 5	Auto-powerdown plus, ready signal	16-pin SSOP
TRSF3221		1	1	±15-kV HBM	3.3 or 5	Auto-powerdown	16-pin SOIC, SSOP, TSSOP
TRSF3223		2	2	±15-kV HBM	3.3 or 5	Auto-powerdown, enable signal	20-pin SOIC, SSOP, TSSOP
TRSF3222		2	2	±15-kV HBM	3.3 or 5	Enable, powerdown signal	20-pin SOIC, SSOP, TSSOP
TRSF3232		2	2	±15-kV HBM	3.3 or 5	Low pin count	16-pin SOIC, SSOP, TSSOP
TRSF3238		5	3	±15-kV HBM	3.3 or 5	Auto-powerdown plus	28-pin SOIC, SSOP, TSSOP
TRSF3243		3	5	±15-kV HBM	3.3 or 5	Auto-powerdown	28-pin SOIC, SSOP, TSSOP

Absolute Maximum Ratings[1]

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
V_{CC}	Supply voltage range[2]			−0.3	6	V
V+	Positive output supply voltage range[2]			−0.3	7	V
V−	Negative output supply voltage range[2]			0.3	−7	V
V+ − V−	Supply voltage difference[2]				13	V
V_I	Input voltage range	Driver (FORCEOFF, FORCEON, EN)		−0.3	6	V
		Receiver		−25	25	
V_O	Output voltage range	Driver		−13.2	13.2	V
		Receiver (INVALID)		−0.3	V_{CC} + 0.3	
θ_{JA}	Package thermal impedance[3][4]	DB package			82	°C/W
		PW package			108	
T_J	Operating virtual junction temperature				150	°C
T_{stg}	Storage temperature range			−65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages are with respect to network GND.
(3) Maximum power dissipation is a function of T_J(max), θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
(4) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions[1]

See Figure 6

				MIN	NOM	MAX	UNIT
	Supply voltage		V_{CC} = 3.3 V	3	3.3	3.6	V
			V_{CC} = 5 V	4.5	5	5.5	
V_{IH}	Driver and control high-level input voltage	DIN, FORCEOFF, FORCEON, EN	V_{CC} = 3.3 V	2			V
			V_{CC} = 5 V	2.4			
V_{IL}	Driver and control low-level input voltage	DIN, FORCEOFF, FORCEON, EN				0.8	V
V_I	Driver and control input voltage	DIN, FORCEOFF, FORCEON		0		5.5	V
V_I	Receiver input voltage			−25		25	V
T_A	Operating free-air temperature	TRSF3221EI		−40		85	°C
		TRSF3221EC		0		70	

(1) Test conditions are C1–C4 = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2–C4 = 0.33 μF at V_{CC} = 5 V ± 0.5 V.

Electrical Characteristics[1]

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER		TEST CONDITIONS	MIN	TYP[2]	MAX	UNIT
I_I	Input leakage current	FORCEOFF, FORCEON, EN			±0.01	±1	μA
I_{CC}	Supply current (T_A = 25°C)	Auto-powerdown disabled	No load, FORCEOFF and FORCEON at V_{CC}		0.3	1	mA
		Powered off	No load, FORCEOFF at GND		1	10	μA
		Auto-powerdown enabled	No load, FORCEOFF at V_{CC}, FORCEON at GND, All RIN are open or grounded		1	10	

(1) Test conditions are C1–C4 = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2–C4 = 0.33 μF at V_{CC} = 5 V ± 0.5 V.
(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

TRSF3221E
3-V TO 5.5-V SINGLE-CHANNEL RS-232 1-Mbit/s LINE DRIVER/RECEIVER
WITH ±15-kV IEC ESD PROTECTION

TEXAS
INSTRUMENTS
www.ti.com

SLLS822−JULY 2007

DRIVER SECTION

Electrical Characteristics[1]

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST CONDITIONS		MIN	TYP[2]	MAX	UNIT
V_{OH}	High-level output voltage	DOUT at R_L = 3 kΩ to GND,	DIN = GND	5	5.4		V
V_{OL}	Low-level output voltage	DOUT at R_L = 3 kΩ to GND,	DIN = V_{CC}	−5	−5.4		V
I_{IH}	High-level input current	V_I = V_{CC}			±0.01	±1	µA
I_{IL}	Low-level input current	V_I at GND			±0.01	±1	µA
I_{OS}	Short-circuit output current[3]	V_{CC} = 3.6 V,	V_O = 0 V		±35	±60	mA
		V_{CC} = 5.5 V,	V_O = 0 V		±35	±90	
r_o	Output resistance	V_{CC}, V+, and V− = 0 V,	V_O = ±2 V	300	10M		Ω
I_{off}	Output leakage current	$\overline{FORCEOFF}$ = GND	V_O = ±12 V, V_{CC} = 3 V to 3.6 V			±25	µA
			V_O = ±10 V, V_{CC} = 4.5 V to 5.5 V			±25	

(1)   Test conditions are C1–C4 = 0.1 µF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 µF, C2–C4 = 0.33 µF at V_{CC} = 5 V ± 0.5 V.
(2)   All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.
(3)   Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

Switching Characteristics[1]

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST CONDITIONS			MIN	TYP[2]	MAX	UNIT
	Maximum data rate (see Figure 1)	R_L = 3 kΩ	C_L = 1000 pF		250			kbit/s
			C_L = 250 pF,	V_{CC} = 3 V to 4.5 V	1000			
			C_L = 1000 pF,	V_{CC} = 4.5 V to 5.5 V	1000			
$t_{sk(p)}$	Pulse skew[3]	C_L = 150 pF to 2500 pF,	R_L = 3 kΩ to 7 kΩ,	See Figure 2		100		ns
SR(tr)	Slew rate, transition region (see Figure 1)	V_{CC} = 3.3 V,	R_L = 3 kΩ to 7 kΩ,	C_L = 150 pF to 1000 pF	18		150	V/µs

(1)   Test conditions are C1–C4 = 0.1 µF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 µF, C2–C4 = 0.33 µF at V_{CC} = 5 V ± 0.5 V.
(2)   All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.
(3)   Pulse skew is defined as |t_{PLH} − t_{PHL}| of each channel of the same device.

ESD Protection

TERMINAL		TEST CONDITIONS	TYP	UNIT
NAME	NO.			
DOUT	13	HBM	±15	kV
		IEC 61000-4-2 Contact Discharge	±8	
		IEC 61000-4-2 Air-Gap Discharge	±15	

Submit Documentation Feedback

www.ti.com

RECEIVER SECTION

Electrical Characteristics[1]

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

PARAMETER		TEST CONDITIONS	MIN	TYP[2]	MAX	UNIT
V_{OH}	High-level output voltage	I_{OH} = −1 mA	V_{CC} − 0.6 V	V_{CC} − 0.1 V		V
V_{OL}	Low-level output voltage	I_{OL} = 1.6 mA			0.4	V
V_{IT+}	Positive-going input threshold voltage	V_{CC} = 3.3 V		1.6	2.4	V
		V_{CC} = 5 V		1.9	2.4	
V_{IT-}	Negative-going input threshold voltage	V_{CC} = 3.3 V	0.6	1.1		V
		V_{CC} = 5 V	0.8	1.4		
V_{hys}	Input hysteresis (V_{IT+} − V_{IT-})			0.5		V
I_{off}	Output leakage current	$\overline{FORCEOFF}$ = 0 V		±0.05	±10	µA
r_i	Input resistance	V_I = ±3 V to ±25 V	3	5	7	kΩ

(1) Test conditions are C1–C4 = 0.1 µF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 µF, C2–C4 = 0.33 µF at V_{CC} = 5 V ± 0.5 V.
(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

Switching Characteristics[1]

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 6)

PARAMETER		TEST CONDITIONS	TYP[2]	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	C_L = 150 pF, See Figure 3	150	ns
t_{PHL}	Propagation delay time, high- to low-level output	C_L = 150 pF, See Figure 3	150	ns
t_{en}	Output enable time	C_L = 150 pF, R_L = 3 kΩ, See Figure 4	200	ns
t_{dis}	Output disable time	C_L = 150 pF, R_L = 3 kΩ, See Figure 4	200	ns
$t_{sk(p)}$	Pulse skew[3]	See Figure 3	50	ns

(1) Test conditions are C1–C4 = 0.1 µF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 µF, C2–C4 = 0.33 µF at V_{CC} = 5 V ± 0.5 V.
(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.
(3) Pulse skew is defined as |t_{PLH} − t_{PHL}| of each channel of the same device.

ESD Protection

TERMINAL		TEST CONDITIONS	TYP	UNIT
NAME	NO.			
RIN	8	HBM	±15	kV
		IEC 61000-4-2 Contact Discharge	±8	
		IEC 61000-4-2 Air-Gap Discharge	±15	

AUTO-POWERDOWN SECTION

Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

PARAMETER		TEST CONDITIONS	MIN	MAX	UNIT
$V_{T+(valid)}$	Receiver input threshold for $\overline{INVALID}$ high-level output voltage	FORCEON = GND, $\overline{FORCEOFF}$ = V_{CC}		2.7	V
$V_{T-(valid)}$	Receiver input threshold for $\overline{INVALID}$ high-level output voltage	FORCEON = GND, $\overline{FORCEOFF}$ = V_{CC}	−2.7		V
$V_{T(invalid)}$	Receiver input threshold for $\overline{INVALID}$ low-level output voltage	FORCEON = GND, $\overline{FORCEOFF}$ = V_{CC}	−0.3	0.3	V
V_{OH}	$\overline{INVALID}$ high-level output voltage	I_{OH} = −1 mA, FORCEON = GND, $\overline{FORCEOFF}$ = V_{CC}	V_{CC} − 0.6		V
V_{OL}	$\overline{INVALID}$ low-level output voltage	I_{OL} = 1.6 mA, FORCEON = GND, $\overline{FORCEOFF}$ = V_{CC}		0.4	V

Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

PARAMETER		TYP[1]	UNIT
t_{valid}	Propagation delay time, low- to high-level output	1	µs
$t_{invalid}$	Propagation delay time, high- to low-level output	30	µs
t_{en}	Supply enable time	100	µs

(1) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

PARAMETER MEASUREMENT INFORMATION
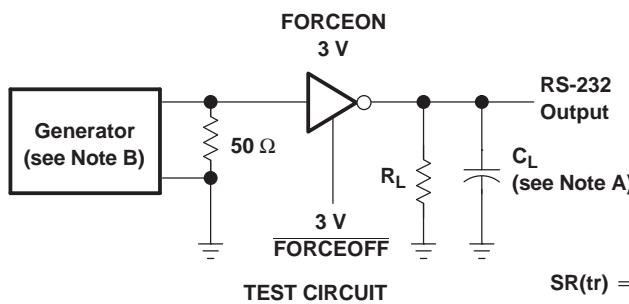
$$SR(tr) = \frac{6\ V}{t_{THL}\ or\ t_{TLH}}$$
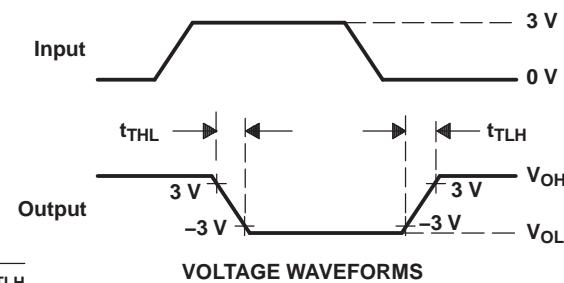
NOTES: A. C_L includes probe and jig capacitance.
        B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_O = 50 Ω, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 1. Driver Slew Rate
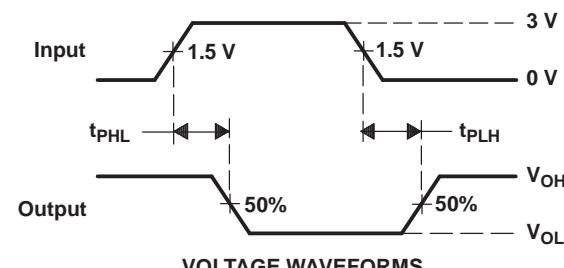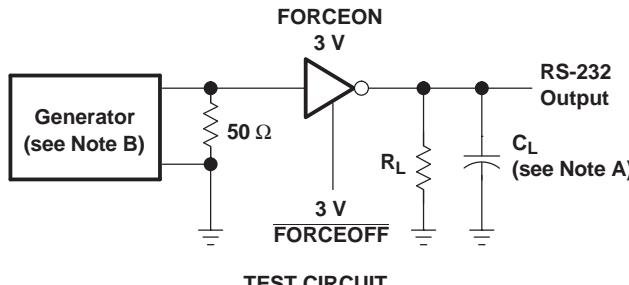
NOTES: A. C_L includes probe and jig capacitance.
        B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_O = 50 Ω, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 2. Driver Pulse Skew
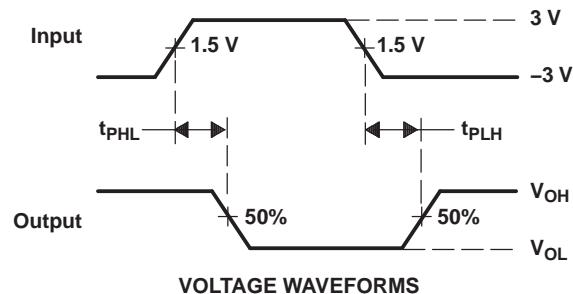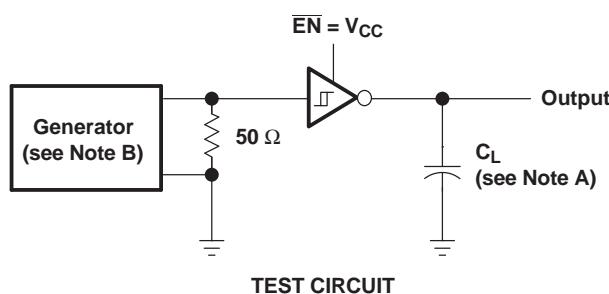
NOTES: A. C_L includes probe and jig capacitance.
        B. The pulse generator has the following characteristics: Z_O = 50 Ω, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 3. Receiver Propagation Delay Times
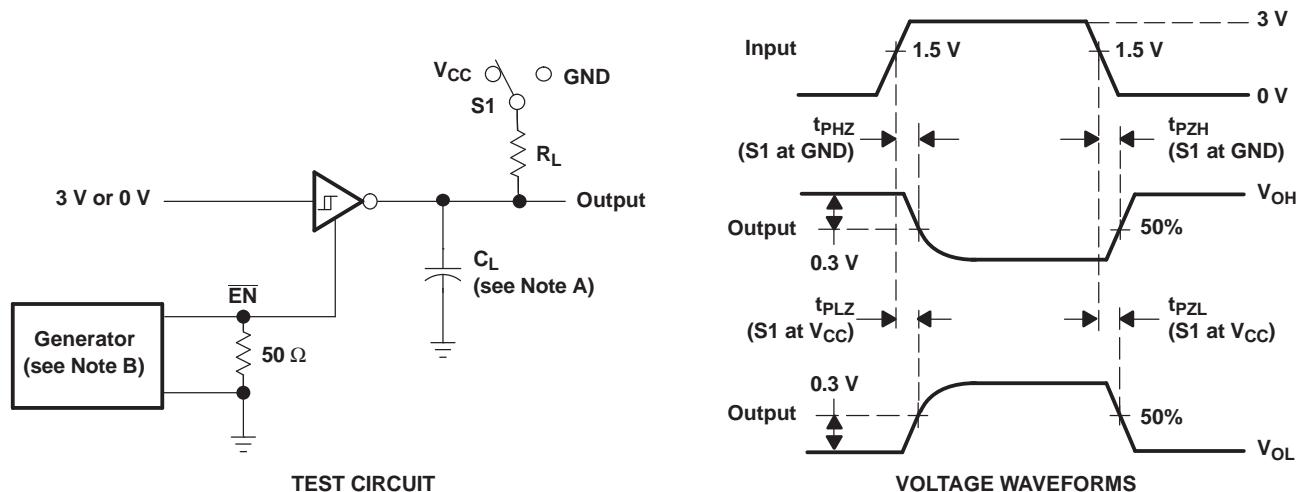
TRSF3221E
3-V TO 5.5-V SINGLE-CHANNEL RS-232 1-Mbit/s LINE DRIVER/RECEIVER
WITH ±15-kV IEC ESD PROTECTION

SLLS822−JULY 2007

TEXAS
INSTRUMENTS
www.ti.com

PARAMETER MEASUREMENT INFORMATION (continued)

TEST CIRCUIT

VOLTAGE WAVEFORMS

NOTES: A. C_L includes probe and jig capacitance.
B. The pulse generator has the following characteristics: Z_O = 50 Ω, 50% duty cycle, t_r ≤ 10 ns, t_f ≤ 10 ns.
C. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
D. t_{PZL} and t_{PZH} are the same as t_{en}.

Figure 4. Receiver Enable and Disable Times

PARAMETER MEASUREMENT INFORMATION (continued)

TEST CIRCUIT

VOLTAGE WAVEFORMS
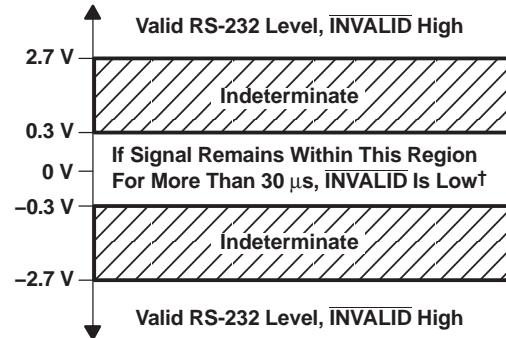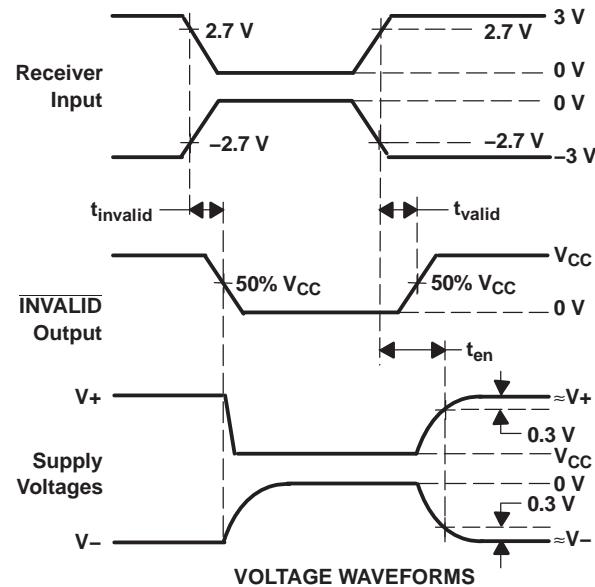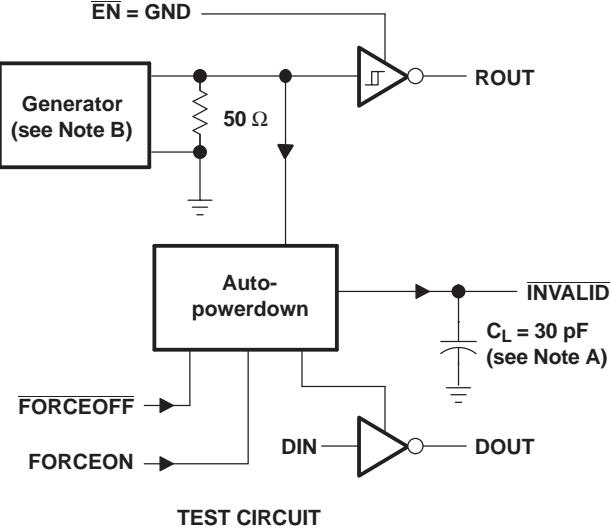
† Auto-powerdown disables drivers and reduces supply
current to 1 μA.

NOTES: A. C_L includes probe and jig capacitance.
B. The pulse generator has the following characteristics: PRR = 5 kbit/s, Z_O = 50 Ω, 50% duty cycle, t_r ≤ 10 ns, t_f ≤ 10 ns.

Figure 5. INVALID Propagation Delay Times and Driver Enabling Time

TRSF3221E
3-V TO 5.5-V SINGLE-CHANNEL RS-232 1-Mbit/s LINE DRIVER/RECEIVER
WITH ±15-kV IEC ESD PROTECTION
SLLS822–JULY 2007

**TEXAS
INSTRUMENTS**
www.ti.com

APPLICATION INFORMATION
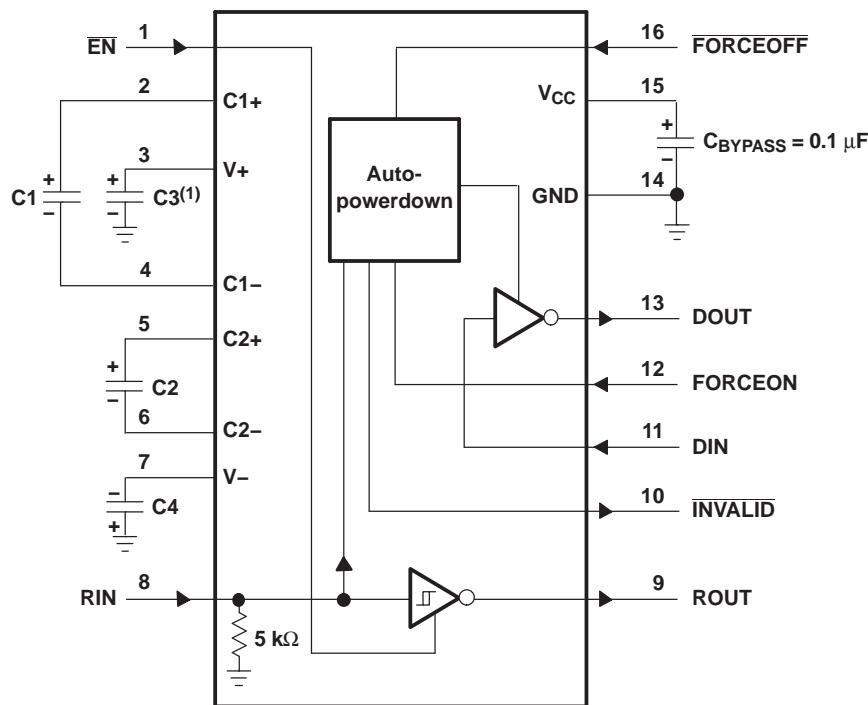
(1) C3 can be connected to V_{CC} or GND.
NOTES: A.   Resistor values shown are nominal.
               B.   Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

V_{CC} vs CAPACITOR VALUES

V_{CC}	C1	C2, C3, and C4
3.3 V ± 0.3 V	0.1 μF	0.1 μF
5 V ± 0.5 V	0.047 μF	0.33 μF
3 V to 5.5 V	0.1 μF	0.47 μF

Figure 6. Typical Operating Circuit and Capacitor Values

Submit Documentation Feedback

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TRSF3221ECDB	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RT21EC	Samples
TRSF3221ECDBG4	ACTIVE	SSOP	DB	16	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RT21EC	Samples
TRSF3221ECDBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RT21EC	Samples
TRSF3221ECDBRG4	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RT21EC	Samples
TRSF3221ECPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RT21EC	Samples
TRSF3221ECPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RT21EC	Samples
TRSF3221EIDB	OBSOLETE	SSOP	DB	16		TBD	Call TI	Call TI	-40 to 85		
TRSF3221EIDBG4	OBSOLETE	SSOP	DB	16		TBD	Call TI	Call TI	-40 to 85		
TRSF3221EIDBR	ACTIVE	SSOP	DB	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RT21EI	Samples
TRSF3221EIPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RT21EI	Samples
TRSF3221EIPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RT21EI	Samples
TRSF3221EIPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RT21EI	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

[3] MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

[4] There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

[5] Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

[6] Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS
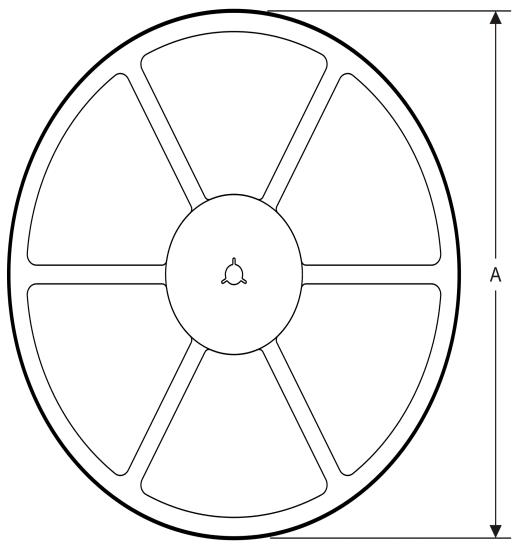
TAPE DIMENSIONS
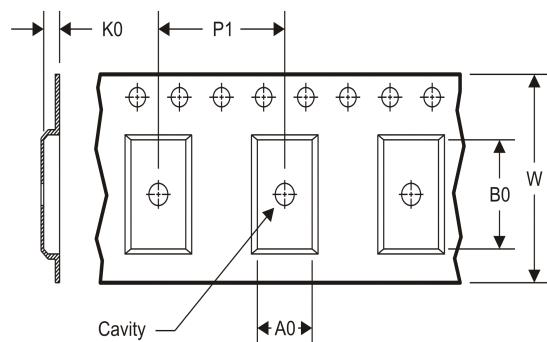
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers
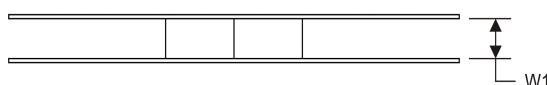
TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRSF3221ECDBR	SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
TRSF3221ECPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TRSF3221EIDBR	SSOP	DB	16	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
TRSF3221EIPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS
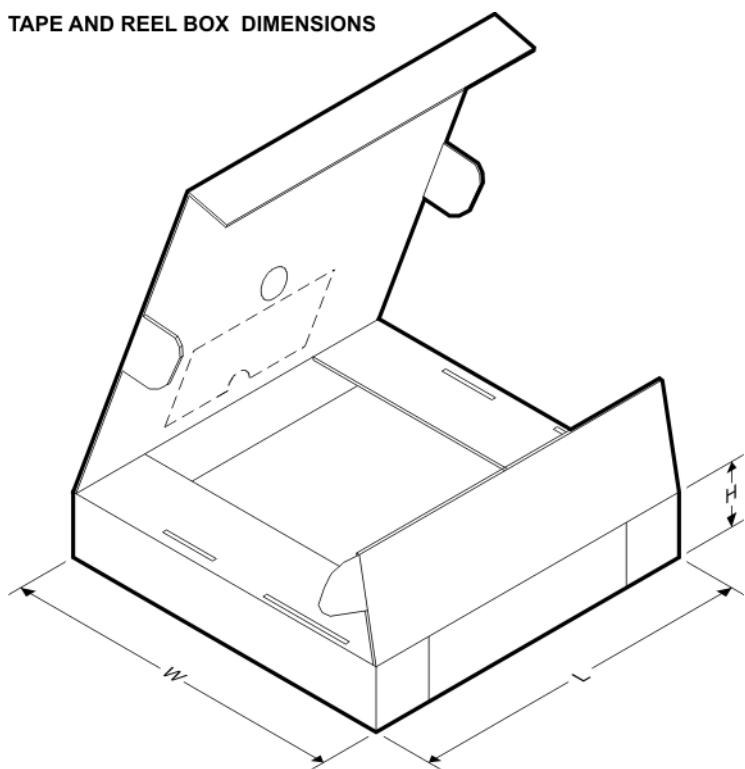
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRSF3221ECDBR	SSOP	DB	16	2000	367.0	367.0	38.0
TRSF3221ECPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
TRSF3221EIDBR	SSOP	DB	16	2000	367.0	367.0	38.0
TRSF3221EIPWR	TSSOP	PW	16	2000	367.0	367.0	35.0

PW (R−PDSO−G16)   PLASTIC SMALL OUTLINE

0,65

0,30
0,19

⊕ 0,10 Ⓜ

16   9

△D 4,50
    4,30

6,60
6,20

1   8

5,10
4,90

△C

0,15 NOM

Gage Plane

0,25

0°−8°

0,75
0,50

1,20 MAX

0,15
0,05

Seating Plane

⌓ 0,10

4040064−4/G 02/11
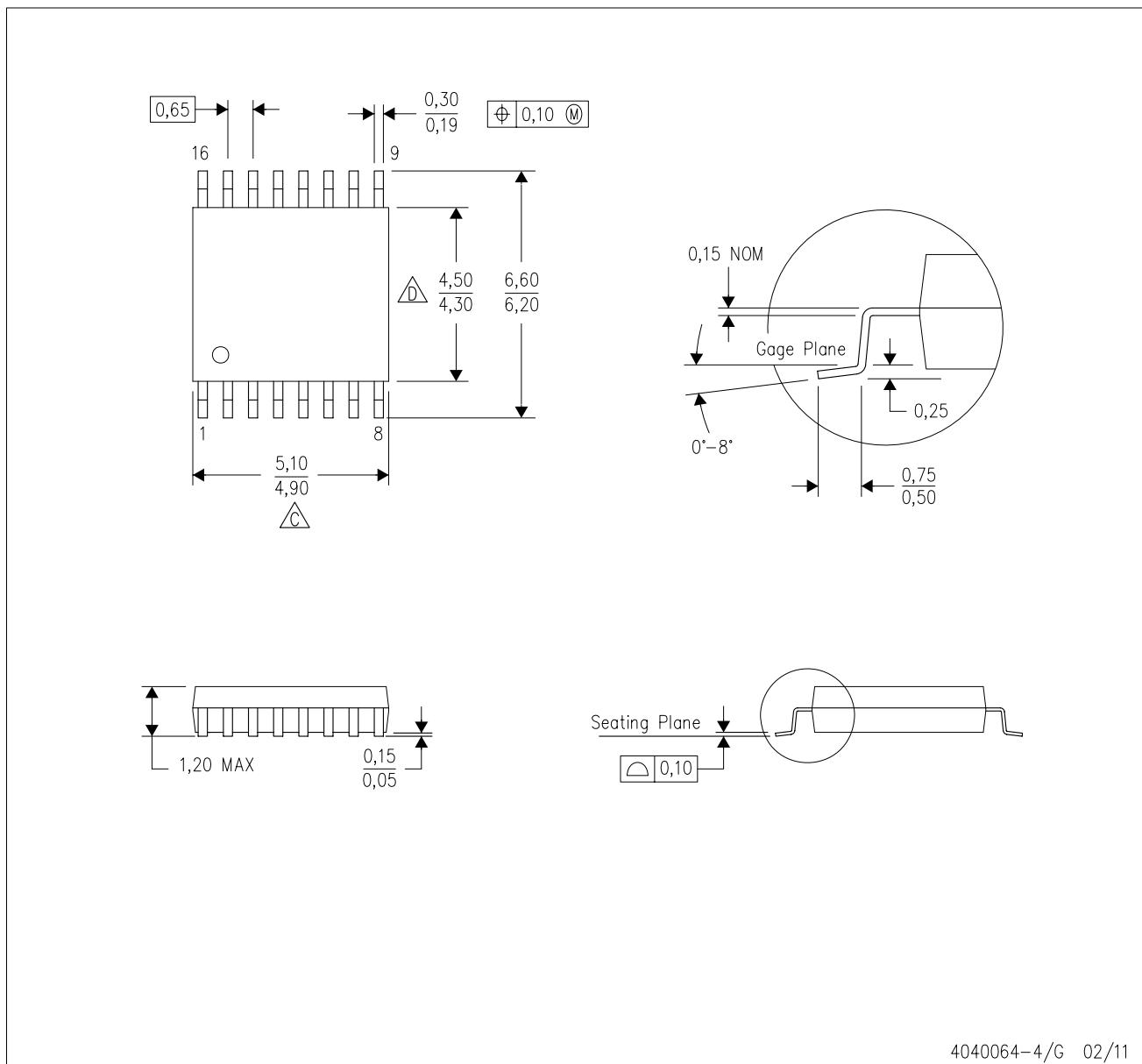
NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M−1994.
          B. This drawing is subject to change without notice.
          △C Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall
              not exceed 0,15 each side.
          △D Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
          E. Falls within JEDEC MO−153

PW (R−PDSO−G16)   PLASTIC SMALL OUTLINE

Example Board Layout
(Note C)

←─ 14x0,65

5,60

Stencil Openings
(Note D)

←─ 16x0,30

←─ 14x0,65

16x1,55

5,60

Example
Non Soldermask Defined Pad

Example
Pad Geometry
(See Note C)

←─ 0,35

1,60

Example
Solder Mask Opening
(See Note E)

←─ 0,07
All Around
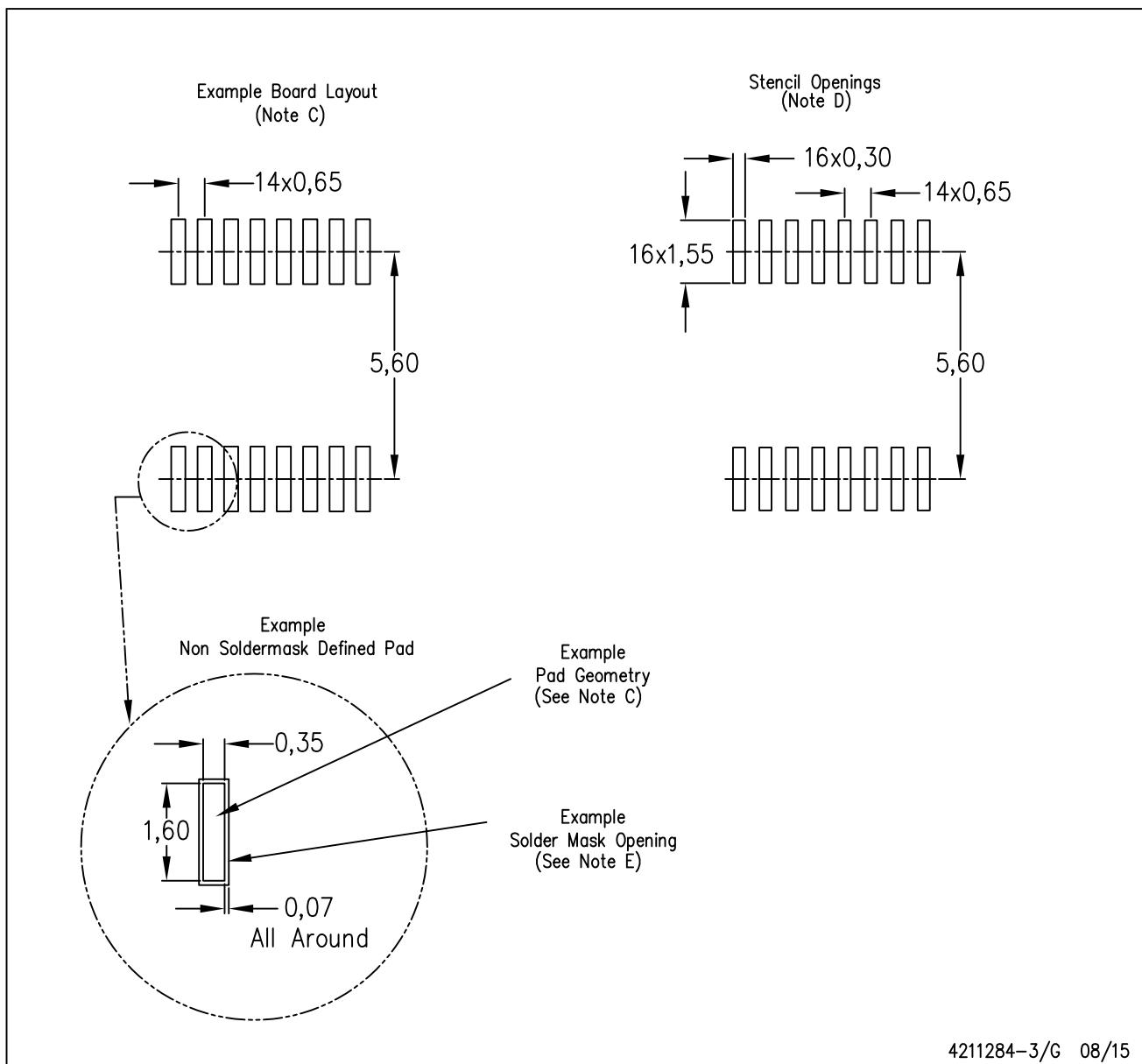
4211284−3/G 08/15

NOTES: A. All linear dimensions are in millimeters.
        B. This drawing is subject to change without notice.
        C. Publication IPC−7351 is recommended for alternate designs.
        D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
            contact their board assembly site for stencil design recommendations. Refer to IPC−7525 for other stencil recommendations.
        E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

TEXAS
INSTRUMENTS
www.ti.com

DB (R-PDSO-G**)   **PLASTIC SMALL-OUTLINE**

28 PINS SHOWN
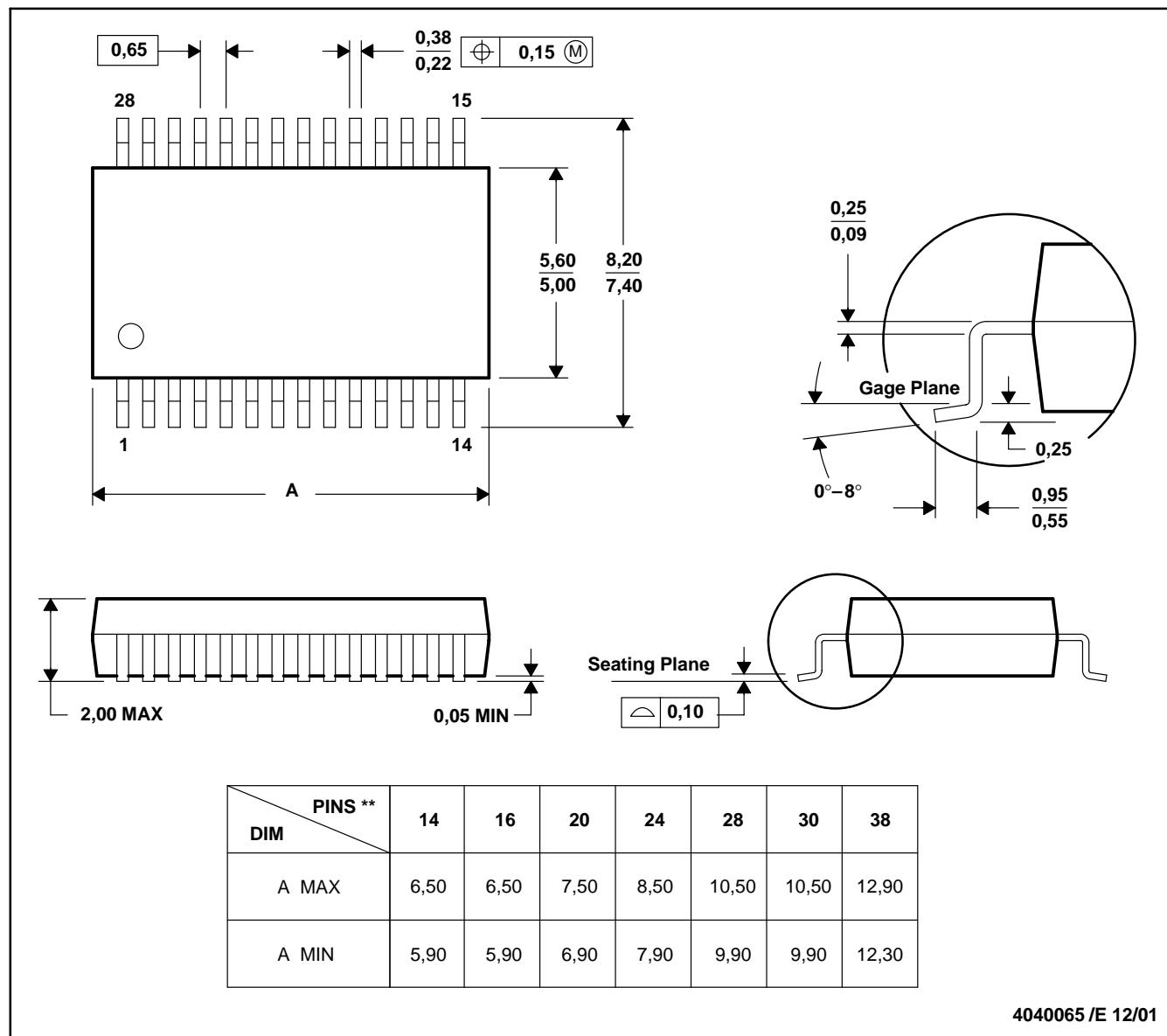
4040065 /E 12/01

DIM \ PINS **	14	16	20	24	28	30	38
A MAX	6,50	6,50	7,50	8,50	10,50	10,50	12,90
A MIN	5,90	5,90	6,90	7,90	9,90	9,90	12,30

NOTES: A. All linear dimensions are in millimeters.
　　　　 B. This drawing is subject to change without notice.
　　　　 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
　　　　 D. Falls within JEDEC MO-150

TEXAS INSTRUMENTS

POST OFFICE BOX 655303 ● DALLAS, TEXAS 75265

IMPORTANT NOTICE

Products		Applications	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	**TI E2E Community**	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconnectivity		